Transistors Panasonic

## 2SA2164

## Silicon PNP epitaxial planar type

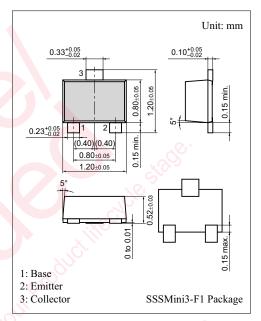
For high-frequency amplification

#### ■ Features

- High transfer ratio f<sub>T</sub>
- SSS-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing.

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	$V_{CBO}$	-30	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-20	V	
Emitter-base voltage (Collector open)	$V_{\mathrm{EBO}}$	<b>-5</b>	V	
Collector current	$I_{C}$	-30	mA	
Collector power dissipation	P <sub>C</sub>	100	mW	
Junction temperature	$T_j$	125	°C	
Storage temperature	T <sub>stg</sub>	-55 to +125	°C	



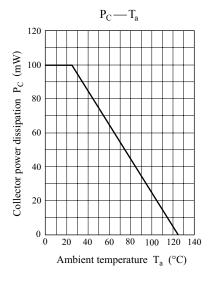
Marking Symbol : E

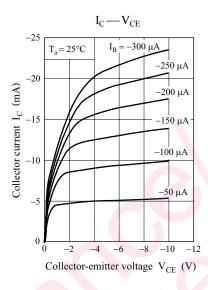
#### ■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

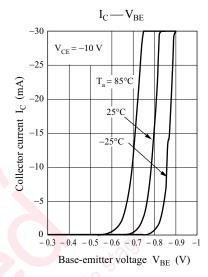
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Base-emitter voltage	$V_{BE}$	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$	16 10	-0.7		V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = -10 \text{ V}, I_{E} = 0$	0)),		-0.1	μА
Collector-emitter cut-off current (Base open)	$I_{CEO}$	$V_{CE} = -20 \text{ V}, I_{B} = 0$		)	-100	μА
Emitter-base cut-off current (Collector open)	$I_{\mathrm{EBO}}$	$V_{EB} = -5 \text{ V}, I_C = 0$	00,		-10	μА
Forward current transfer ratio	h <sub>FE</sub>	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}$	70		220	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = -10  \text{mA}, I_{\rm B} = -1  \text{mA}$		-0.1		V
Transition frequency	$f_T$	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$	150	300		MHz
Noise figure	NF	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 5 \text{ MHz}$		2.8		dB
Reverse transfer impedance	Z <sub>rb</sub>	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 2 \text{ MHz}$		22		Ω
Common-emitter reverse transfer capacitance	C <sub>re</sub>	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 10.7 \text{ MHz}$		1.2		pF

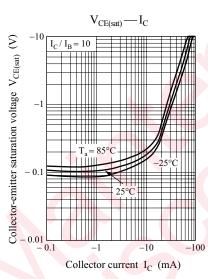
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

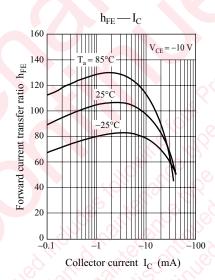
2SA2164 Panasonic

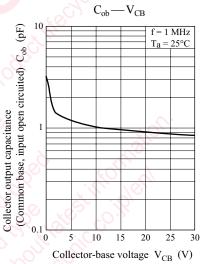












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